# BLF2425M7L100; BLF2425M7LS100 Power LDMOS transistor

**AMMPLEON** 

Rev. 2 — 1 September 2015

Product data sheet

## **Product profile**

### 1.1 General description

100 W LDMOS power transistor for industrial applications at frequencies from 2300 MHz to 2400 MHz.

Table 1. Typical performance

Typical RF performance at  $T_{case} = 25$  °C in a common source class-AB production test circuit.

Test signal	f	I <sub>Dq</sub>	V <sub>DS</sub>	$P_{L(AV)}$	Gp	$\eta_D$	ACPR <sub>885k</sub>	ACPR <sub>5M</sub>
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)	(dBc)
IS-95	2300 to 2400	900	28	20	18	27	-46 <u>[1]</u>	-
1 carrier W-CDMA	2300 to 2400	900	28	30	18.7	33	-	-40 <sup>[2]</sup>

<sup>[1]</sup> Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.

#### 1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R<sub>th</sub> providing excellent thermal stability
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

#### 1.3 Applications

RF power amplifiers for industrial and multi carrier applications in the 2300 MHz to 2400 MHz frequency range

<sup>[2] 3</sup>GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF. Channel bandwidth is 3.84 MHz.

## 2. Pinning information

Table 2. Pinning

Pin	Description		Simplified outline	Graphic symbol
BLF2425	M7L100 (SOT502A)			
1	drain			,
2	gate			
3	source	<u>[1]</u>		2
				3 sym112
BLF2425	M7LS100 (SOT502B)			
1	drain			
2	gate		1 3	1 
3	source	<u>[1]</u>	2 3	2
				3
				sym112

<sup>[1]</sup> Connected to flange.

## 3. Ordering information

Table 3. Ordering information

Type number	Packag	Package			
	Name	Description	Version		
BLF2425M7L100	-	flanged ceramic package; 2 mounting holes; 2 leads	SOT502A		
BLF2425M7LS100	-	earless flanged ceramic package; 2 leads	SOT502B		

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	65	V
$V_{GS}$	gate-source voltage		-0.5	+13	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	200	°C

## 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	$T_{case}$ = 80 °C; $P_L$ = 100 W	0.3	K/W

#### 6. Characteristics

Table 6. DC characteristics

 $T_i = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_{D} = 1 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS}$ = 10 V; $I_{D}$ = 150 mA	1.5	1.8	2.3	V
$I_{DSS}$	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	5	μА
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	25.1	29	-	Α
$I_{GSS}$	gate leakage current	$V_{GS}$ = 11 V; $V_{DS}$ = 0 V	-	-	500	nA
g <sub>fs</sub>	forward transconductance	$V_{DS}$ = 10 V; $I_{D}$ = 5.35 A	-	10.5	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 5.25 \text{ A}$	-	0.1	-	Ω

#### Table 7. RF characteristics

Test signal: single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF, channel bandwidth is 1.2288 MHz;  $f_1$  = 2300 MHz;  $f_2$  = 2400 MHz; RF performance at  $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA;  $T_{case}$  = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	$P_{L(AV)} = 20 W$	17.3	18	-	dB
RLin	input return loss	P <sub>L(AV)</sub> = 20 W	-	-14	-	dB
$\eta_{D}$	drain efficiency	P <sub>L(AV)</sub> = 20 W	22	27	-	%
ACPR <sub>885k</sub>	adjacent channel power ratio (885 kHz)	P <sub>L(AV)</sub> = 20 W	-	-46	-40	dBc

### 7. Test information

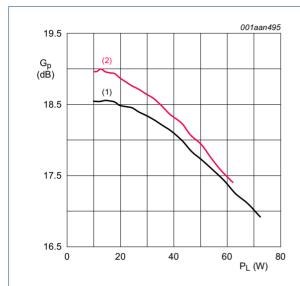
#### 7.1 Ruggedness in class-AB operation

The BLF2425M7L100 and BLF2425M7LS100 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS} = 28 \text{ V}$ ;  $I_{Dq} = 900 \text{ mA}$ ;  $P_L = 100 \text{ W}$  (CW); f = 2300 MHz.

#### 7.2 Graphical data

#### 7.2.1 Single carrier IS-95

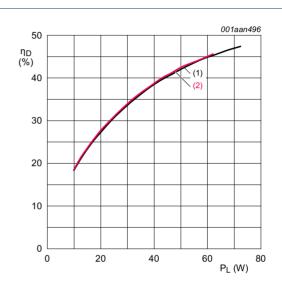
Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.



 $V_{DS} = 28 \text{ V}; I_{Da} = 900 \text{ mA}.$ 

- (1) f = 2300 MHz
- (2) f = 2400 MHz

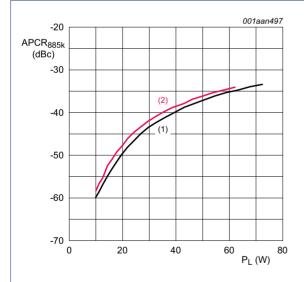
Fig 1. Power gain as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$ 

- (1) f = 2300 MHz
- (2) f = 2400 MHz

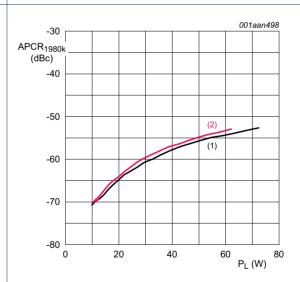
Fig 2. Drain efficiency as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$ 

- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 3. Adjacent channel power ratio (885 kHz) as a function of output power; typical values



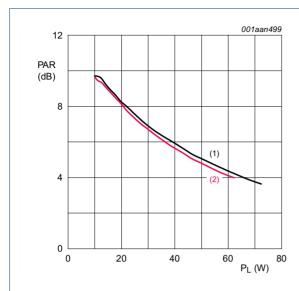
 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$ 

- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 4. Adjacent channel power ratio (1980 kHz) as a function of output power; typical values

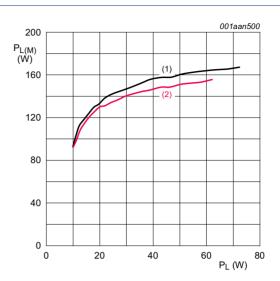
## BLF2425M7L(S)100

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- $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$
- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 5. Peak-to-average power ratio as a function of output power; typical values

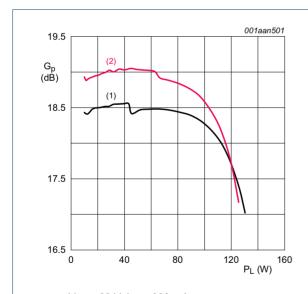


 $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA.

- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 6. Peak power as a function of output power; typical values

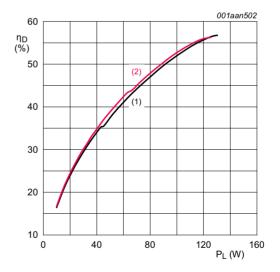
#### 7.2.2 Pulsed CW



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA.

- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 7. Power gain as a function of output power; typical values



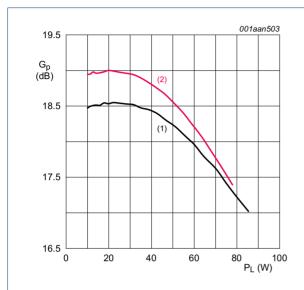
 $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA.

- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 8. Drain efficiency as a function of output power; typical values

#### 7.2.3 Single carrier W-CDMA

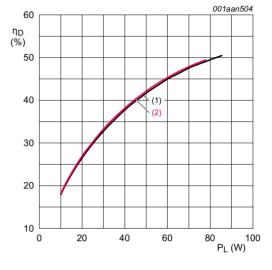
3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF. Channel bandwidth is 3.84 MHz.



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA.

- (1) f = 2300 MHz
- (2) f = 2400 MHz

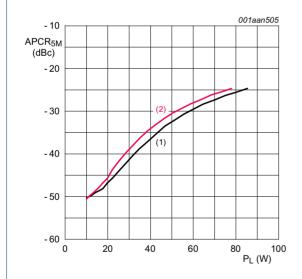
Fig 9. Power gain as a function of output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA.

- (1) f = 2300 MHz
- (2) f = 2400 MHz

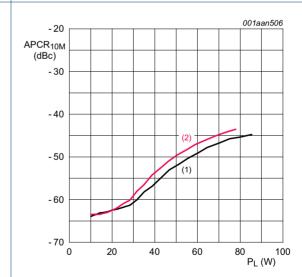
Fig 10. Drain efficiency as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$ 

- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 11. Adjacent channel power ratio (5 MHz) as a function of output power; typical values



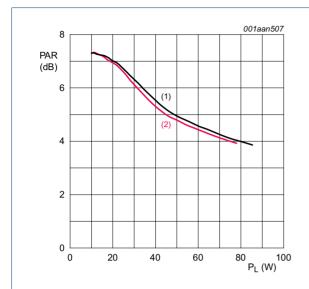
 $V_{DS}$  = 28 V;  $I_{Dq}$  = 900 mA.

- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 12. Adjacent channel power ratio (10 MHz) as a function of output power; typical values

## BLF2425M7L(S)100

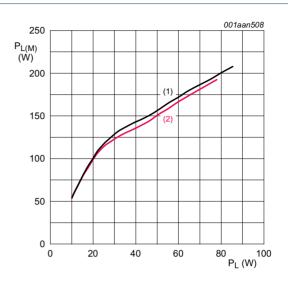
#### **Power LDMOS transistor**



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$ 

- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 13. Peak-to-average power ratio as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$ 

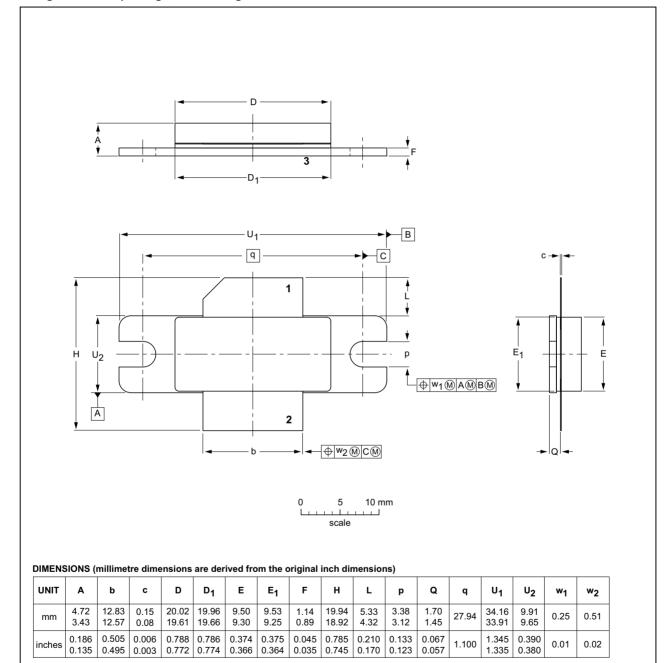
- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 14. Peak output power as a function of output power; typical values

## 8. Package outline

#### Flanged ceramic package; 2 mounting holes; 2 leads

SOT502A

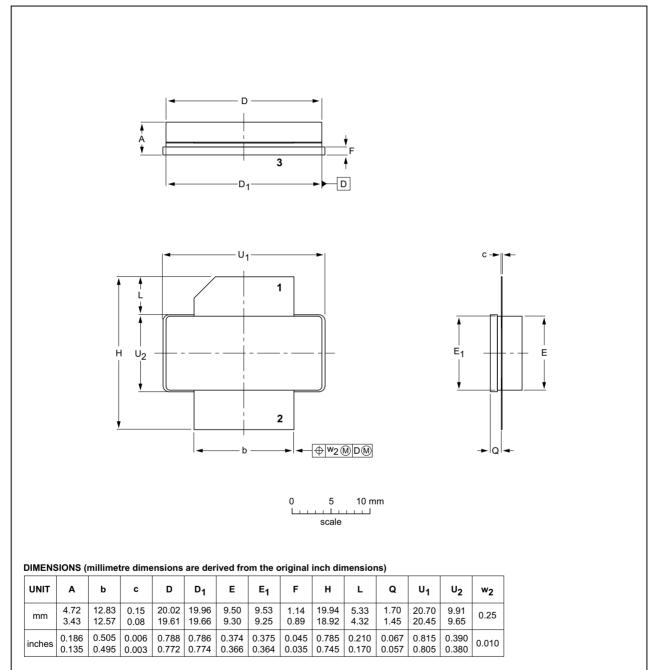


OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT502A						<del>-03-01-10 -</del> 12-05-02

Fig 15. Package outline SOT502A

#### Earless flanged ceramic package; 2 leads

SOT502B



OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	155UE DATE	
SOT502B						<del>07-05-09</del> 12-05-02	

Fig 16. Package outline SOT502B

## 9. Abbreviations

Table 8. Abbreviations

Acronym	Description			
3GPP	3rd Generation Partnership Project			
CCDF	Complementary Cumulative Distribution Function			
CW	Continuous Wave			
DPCH	Dedicated Physical CHannel			
ESD	ElectroStatic Discharge			
IS-95	Interim Standard 95			
LDMOS	Laterally Diffused Metal Oxide Semiconductor			
PAR	Peak-to-Average Ratio			
VSWR	Voltage Standing Wave Ratio			
W-CDMA	Wideband Code Division Multiple Access			

## 10. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BLF2425M7L100_2425M7LS100#2	20150901	Product data sheet	-	BLF2425M7L100_2425M7LS1 00#1		
Modifications:	The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.					
	<ul> <li>Legal texts have been adapted to the new company name where appropri</li> </ul>			pany name wnere appropriate.		
BLF2425M7L100_2425M7LS100#1	20131206	Product data sheet	-	-		

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## BLF2425M7L(S)100

**Power LDMOS transistor** 

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